NSN 5962-01-351-4987

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View Online at https://aerobasegroup.com/nsn/5962-01-351-4987
Overall Length:
1.280 inches
Overall Height:
0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.1 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Bipolar and programmed and high impedance and asynchronous and w/clock and bidirectional
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
200.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Registered and-or logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, high to low level output and 35.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:

Pal

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Test	Data	Document	ŀ
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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